JFET Amplifiers

N-Channel

勝 特 力 材 料 886-3-5753170 胜特力电子(上海) 86-21-54151736 胜特力电子(深圳) 86-755-83298787 Http://www.100y.com.tw



ON Semiconductor®

http://onsemi.com

Features

• Pb-Free Package is Available

MAXIMUM RATINGS

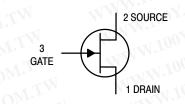
Rating	Symbol	Value	Unit	
Drain-Source Voltage	V _{DS}	25	Vdc	
Gate - Source Voltage	V _{GS}	25	Vdc	

Maximum ratings are those values beyond which device damage can occur. Maximum ratings applied to the device are individual stress limit values (not normal operating conditions) and are not valid simultaneously. If these limits are exceeded, device functional operation is not implied, damage may occur and reliability may be affected.

THERMAL CHARACTERISTICS

Characteristic	Symbol	Max	Unit
Total Device Dissipation (Note 1) T _A = 25°C Derate above 25°C	P _D	225 1.8	mW mW/°C
Thermal Resistance, Junction–to–Ambient	$R_{\theta JA}$	556	°C/W
Total Device Dissipation Alumina Substrate, (Note 2) T _A = 25°C Derate above 25°C	P _D	300 2.4	mW mW/°C
Thermal Resistance, Junction–to–Ambient	$R_{\theta JA}$	417	°C/W
Junction and Storage Temperature	T _J , T _{stg}	-55 to +150	°C

- Device mounted on FR4 glass epoxy printed circuit board using the recommended footprint.
- 2. Alumina = $0.4 \times 0.3 \times 0.024$ in 99.5% alumina.



MARKING DIAGRAM



SOT-23 CASE 318 STYLE 10



x = 1 or 2 M = Date Code

ORDERING INFORMATION

Device	Package	Shipping [†]
BFR30LT1	SOT-23	3000/Tape & Reel
BFR30LT1G	SOT-23 (Pb-Free)	3000/Tape & Reel
BFR31LT1	SOT-23	3000/Tape & Reel
BFR31LT1G	SOT-23 (Pb-Free)	3000/Tape & Reel

†For information on tape and reel specifications, including part orientation and tape sizes, please refer to our Tape and Reel Packaging Specifications Brochure, BRD8011/D.

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WWW.100Y.COM.TW ELECTRICAL CHARACTERISTICS (T_A = 25°C unless otherwise noted)

	Characteristic	WT	Symbol	Min	Max	Unit
OFF CHARACTERISTICS	MWW.Io	COM	WWW	You	COB.	WT
Gate Reverse Current (V _{GS}	; = 10 Vdc, V _{DS} = 0)	COM	I _{GSS}	1.70	0.2	nAdc
Gate Source Cutoff Voltage (I _D =	0.5 nAdc, V _{DS} = 10 Vdc)	BFR30 BFR31	V _{GS(OFF)}	7/200	5.0 2.5	Vdc
M. 100 r. COW.	1.0 mAdc, V _{DS} = 10 Vdc) 50 μAdc, V _{DS} = 10 Vdc)	BFR30 BFR31 BFR30	V _{GS}	-0.7 -	-3.0 -1.3 -4.0	Vdc
W 1007.00M	50μ Adc, $v_{DS} = 10 v_{AC}$	BFR31		W.	-2.0	CO_{M} .
ON CHARACTERISTICS	TIM WILL	1001. COM.1	-1	TIV.	1.100	COM
Zero – Gate – Voltage Drain Current	$(V_{DS} = 10 \text{ Vdc}, V_{GS} = 0)$	BFR30 BFR31	I _{DSS}	4.0 1.0	10 5.0	mAdc
SMALL-SIGNAL CHARACTERISTIC	S	M. In. COM		WV	1111	N.C.C
Forward Transconductance (I _D = 1.0 mAdc, V _{DS} = 10 Vdc, f = 1	.0 kHz)	BFR30 BFR31	Yfs	1.0 1.5	4.0 4.5	mmhos
Forward Transconductance	.0 kHz)		Yfs			mmhos
Forward Transconductance (I _D = 1.0 mAdc, V _{DS} = 10 Vdc, f = 1	.0 kHz) .0 kHz)	BFR31 BFR30	Yfs Yos	1.5 0.5	4.5 -	mmhos µmhos
Forward Transconductance ($I_D = 1.0 \text{ mAdc}$, $V_{DS} = 10 \text{ Vdc}$, $f = 1$ ($I_D = 200 \mu\text{Adc}$, $V_{DS} = 10 \text{ Vdc}$, $f = 1$ Output Admittance ($I_D = 1.0 \text{ mAdc}$, $V_{DS} = 10 \text{ Vdc}$, $f = 1$.0 kHz) .0 kHz)	BFR31 BFR30 BFR31 BFR30 BFR31 'dc, f = 1.0 MHz)	OM.TW OM.TW	1.5 0.5 0.75	4.5 - - 25	100X.

TYPICAL CHARACTERISTICS

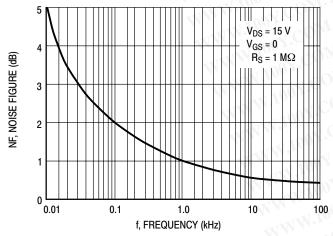
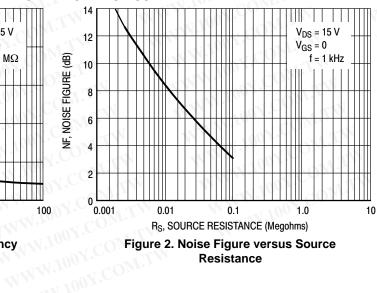


Figure 1. Noise Figure versus Frequency



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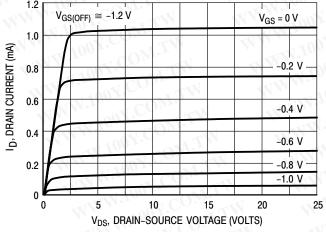


Figure 3. Typical Drain Characteristics

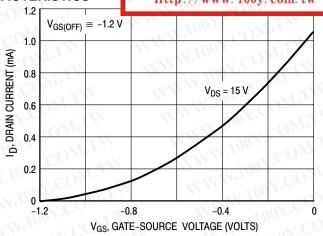


Figure 4. Common Source Transfer Characteristics

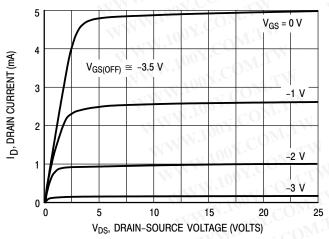


Figure 5. Typical Drain Characteristics

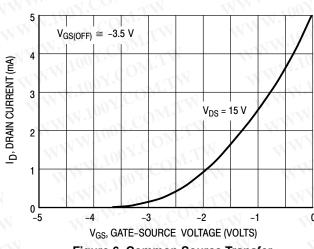


Figure 6. Common Source Transfer Characteristics

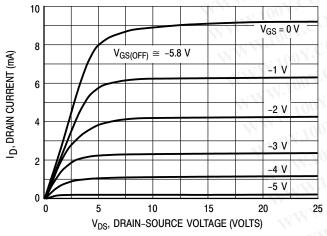


Figure 7. Typical Drain Characteristics

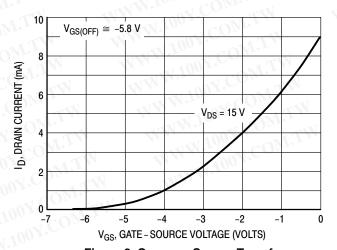


Figure 8. Common Source Transfer Characteristics

Note: Graphical data is presented for dc conditions. Tabular data is given for pulsed conditions (Pulse Width = 630 ms, Duty Cycle = 10%). Under dc conditions, self heating in higher I_{DSS} units reduces I_{DSS}.

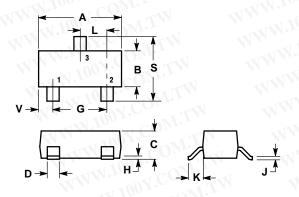
PACKAGE DIMENSIONS

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SOT-23 (TO-236) CASE 318-08 ISSUE AK



NOTES

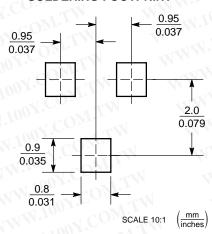
- DIMENSIONING AND TOLERANCING PER ANSI Y14.5M, 1982.
- CONTROLLING DIMENSION: INCH.
- MAXIMUM LEAD THICKNESS INCLUDES LEAD FINISH THICKNESS. MINIMUM LEAD THICKNESS IS THE MINIMUM THICKNESS OF BASE MATERIAL.
- 318–01 THRU –07 AND –09 OBSOLETE, NEW STANDARD 318–08.

V:I	INC	CHES	MILLIM	IETERS	
DIM	MIN	MAX	MIN	MAX	
Α	0.1102	0.1197	2.80	3.04	
В	0.0472	0.0551	1.20	1.40	
С	0.0350	0.0440	0.89	1.11	
D	0.0150	0.0200	0.37	0.50	
G	0.0701	0.0807	1.78	2.04	
H	0.0005	0.0040	0.013	0.100	
J	0.0034	0.0070	0.085	0.177	
K	0.0140	0.0285	0.35	0.69	
L	0.0350	0.0401	0.89	1.02	
S	0.0830	0.1039	2.10	2.64	
٧	0.0177	0.0236	0.45	0.60	

STYLE 10: PIN 1. DRAIN

SOURCE 3. GATE

SOLDERING FOOTPRINT*



*For additional information on our Pb-Free strategy and soldering details, please download the ON Semiconductor Soldering and Mounting Techniques Reference Manual, SOLDERRM/D.

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